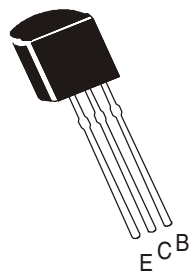


NPN SILICON PLANAR EPITAXIAL TRANSISTOR

CSD2470



TO-92
Plastic Package

ABSOLUTE MAXIMUM RATINGS

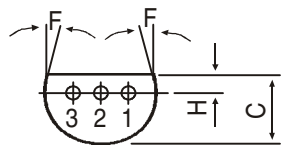
DESCRIPTION	SYMBOL	VALUE	UNITS
Collector Base Voltage	V_{CBO}	15	V
Collector Emitter Voltage	V_{CEO}	10	V
Emitter Base Voltage	V_{EBO}	7.0	V
Collector Current	I_C	5.0	A
Collector Current Peak	$*I_{CP}$	8.0	A
Collector Power Dissipation @ $T_a=25^\circ\text{C}$	P_C	0.4	W
Junction Temperature	T_j	150	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	- 55 to +150	$^\circ\text{C}$

*Single Pulse=10ms

ELECTRICAL CHARACTERISTICS ($T_a=25^\circ\text{C}$ unless specified otherwise)

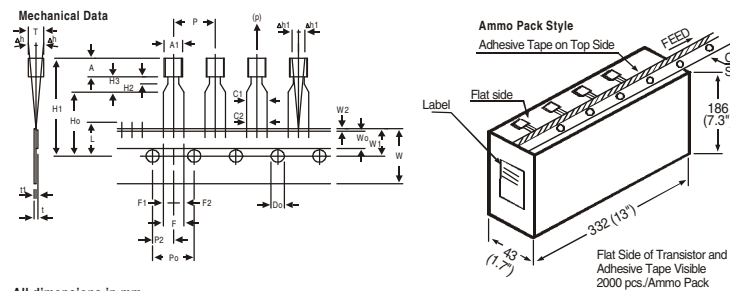
DESCRIPTION	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNITS
Collector Base Voltage	V_{CBO}	$I_C=50\mu\text{A}$, $I_E=0$	15			V
Collector Emitter Voltage	V_{CEO}	$I_C=1\text{mA}$, $I_B=0$	10			V
Emitter Base Voltage	V_{EBO}	$I_E=50\mu\text{A}$, $I_C=0$	7			V
Collector Cut off Current	I_{CBO}	$V_{CB}=10\text{V}$, $I_E=0$			0.1	μA
Emitter Cut off Current	I_{EBO}	$V_{EB}=6\text{V}$, $I_C=0$			0.5	μA
Collector Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=3\text{A}$, $I_B=0.1\text{A}$			0.5	V
DC Current Gain	h_{FE}	$V_{CE}=2\text{V}$, $I_C=2\text{A}$	270		820	
Transition Frequency	f_T	$I_C=0.05\text{A}$, $V_{CE}=6\text{V}$, $f=100\text{MHz}$		170		MHz
Output Capacitance	C_{ob}	$I_E=0$, $V_{CB}=10\text{V}$, $f=1\text{MHz}$		30		pF

TO-92 Transistors on Tape and Ammo Pack



1. BASE
2. COLLECTOR
3. EMITTER

All dimensions in mm.



ITEM		SYMBOL	SPECIFICATION				REMARKS
			MIN.	NOM.	MAX.	TOL.	
BODY WIDTH		A1	4.0		4.8		CUMULATIVE PITCH ERROR 1.0 mm/20 PT
BODY HEIGHT		A	4.8		5.2		
BODY THICKNESS		T	3.9		4.2		
PITCH OF COMPONENT		P		12.7		± 1.0	
FEED HOLE PITCH		Po		12.7		± 0.3	
FEED HOLE CENTRE TO COMPONENT CENTRE		P2		6.35		± 0.4	TO BE MEASURED AT BOTTOM OF CLINCH
DISTANCE BETWEEN OUTER LEADS		F		5.08		+ 0.6 - 0.2	AT TOP OF BODY AT TOP OF BODY
COMPONENT ALIGNMENT SIDE VIEW		Δh		0	1.0		
COMPONENT ALIGNMENT FRONT VIEW		Δh1		0	1.3		
TAPE WIDTH		W		18		± 0.5	
HOLD-DOWN TAPE WIDTH		Wo		6		± 0.2	
HOLE POSITION		W1		9		+ 0.7 - 0.5	t1 0.3-0.6
HOLD-DOWN TAPE POSITION		W2		0.5		± 0.2	
LEAD WIRE CLINCH HEIGHT		Ho		16		± 0.5	
COMPONENT HEIGHT		H1			23.25		
LENGTH OF SNIPPED LEADS		L			11.0		
FEED HOLE DIAMETER		Do		4		± 0.2	
TOTAL TAPE THICKNESS		t			1.2		
LEAD - TO - LEAD DISTANCE		F1, F2		2.54		+ 0.4 - 0.1	
STAND OFF		H2	0.45		1.45		
CLINCH HEIGHT		H3			3.0		
LEAD PARALLELISM		C1 - C2			0.22		
PULL - OUT FORCE		(P)	6N				

NOTES

1. Maximum alignment deviation between leads will not be greater than 0.2mm.
2. Maximum non-cumulative variation between tape feed holes shall not exceed 1 mm in 20 pitches.
3. Holddown tape will not exceed beyond the edge(s) of carrier tape and there shall be no exposure of adhesive.
4. There will be no more than three (3) consecutive missing components in a tape.
5. A tape trailer, having at least three feed holes are provided after the last component in a tape.
6. Splices should not interfere with the sprocket feed holes.

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
TO-92 Bulk	1K/polybag	200 gm/1K pcs	3" x 7.5" x 7.5"	5K	17" x 15" x 13.5"	80K	23 kgs
TO-92 T&A	2K/ammo box	645 gm/2K pcs	12.5" x 8" x 1.8"	2K	17" x 15" x 13.5"	32K	12.5 kgs

Disclaimer

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